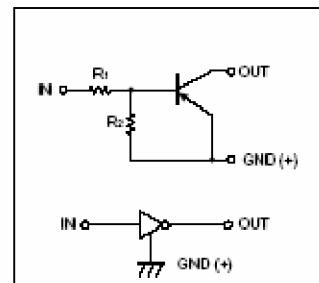


DIGITAL TRANSISTOR (PNP)

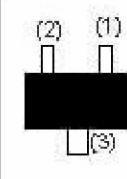
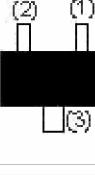
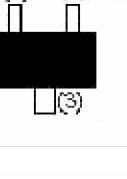
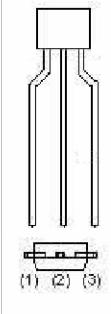
• Equivalent circuit



FEATURES

1. Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
2. The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects.
3. Only the on/off conditions need to be set for operation, making device design easy.

PIN CONNECTIONS AND MARKING

DTA144EE		1.IN 2.GND 3.OUT
SOT-523	Addreviated symbol: 16	
DTA144EKA		1.IN 2.GND 3.OUT
SOT-23-3L	Addreviated symbol: 16	
DTA144ECA		1.IN 2.GND 3.OUT
SOT-23	Addreviated symbol: 16	
DTA144ESA		1.GND 2.OUT 3.IN
TO-92S		

Absolute maximum ratings(Ta=25°C)

Parameter	Symbol	Limits (DTA144E□)					Unit				
		E	UA	KA	CA	SA					
Supply voltage	V _{CC}	-50					V				
Input voltage	V _{IN}	-40~+10					V				
Output current	I _O	-30					mA				
	I _{C(MAX)}	-100									
Power dissipation	P _d	150	200		300		mW				
Junction temperature	T _j	150					°C				
Storage temperature	T _{stg}	-55~150					°C				

Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ	Max.	Unit	Conditions
Input voltage	V _{I(off)}			-0.5	V	V _{CC} =-5V ,I _O =-100μA
	V _{I(on)}	-3				V _O =-0.3V ,I _O =-2mA
Output voltage	V _{O(on)}			-0.3	V	I _O /I _i =-10mA/-0.5mA
Input current	I _i			-0.18	mA	V _i =-5V
Output current	I _{O(off)}			-0.5	μA	V _{CC} =-50V ,V _i =0
DC current gain	G _i	68				V _O =-5V ,I _O =-5mA
Input resistance	R _i	32.9	47	61.1	KΩ	
Resistance ratio	R ₂ /R ₁	0.8	1	1.2		
Transition frequency	f _T		250		MHz	V _O =-10V ,I _O =-5mA,f=100MHz

Typical Characteristics

